

Cascadable Silicon Bipolar MMIC Amplifier

Technical Data

MSA-0504

Features

- **Cascadable 50 Ω Gain Block**
- **High Output Power:**
18.0 dBm Typical $P_{1\text{ dB}}$ at
1.0 GHz
- **Low Distortion:**
29.0 dBm Typical IP_3 at 1.0 GHz
- **7.0 dB Typical Gain at
1.0 GHz**
- **Low Cost Plastic Package**

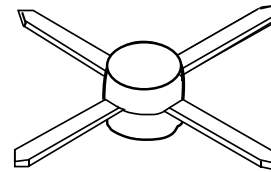
Description

The MSA-0504 is a high performance medium power silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed

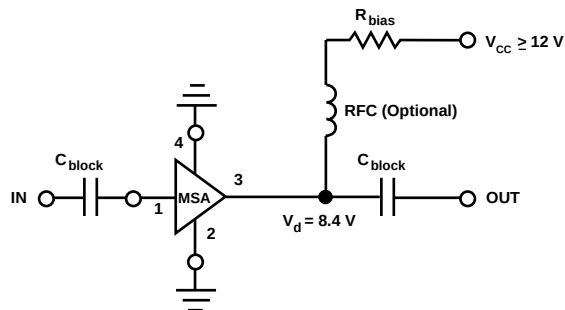
in a low cost plastic package. This MMIC is designed for use as a general purpose 50 Ω gain block. Typical applications include narrow and broad band IF and RF amplifiers in commercial systems.

The MSA-series is fabricated using HP's 10 GHz f_T , 25 GHz f_{MAX} , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

04A Plastic Package



Typical Biasing Configuration



MSA-0504 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]
Device Current	135 mA
Power Dissipation ^[2,3]	1.5 W
RF Input Power	+25 dBm
Junction Temperature	200°C
Storage Temperature	-65 to 150°C

Thermal Resistance^[2,4]:

$$\theta_{jc} = 75^{\circ}\text{C/W}$$

Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2. $T_{\text{CASE}} = 25^{\circ}\text{C}$.
3. Derate at 13.3 mW/°C for $T_{\text{C}} > 88^{\circ}\text{C}$.
4. See MEASUREMENTS section "Thermal Resistance" for more information.

Electrical Specifications^[1], $T_{\text{A}} = 25^{\circ}\text{C}$

Symbol	Parameters and Test Conditions: $I_{\text{d}} = 80 \text{ mA}$, $Z_{\text{o}} = 50 \Omega$	Units	Min.	Typ.	Max.
$P_{1 \text{ dB}}$	Output Power at 1 dB Gain Compression $f = 0.5 \text{ GHz}$ $f = 1.0 \text{ GHz}$	dBm dBm	16.0	19.0 18.0	
G_{P}	Power Gain ($ S_{21} ^2$) $f = 0.5 \text{ GHz}$ $f = 1.0 \text{ GHz}$	dB	6.0	7.5 7.0	
ΔG_{P}	Gain Flatness $f = 0.1 \text{ to } 1.5 \text{ GHz}$	dB		± 0.75	
$f_{3 \text{ dB}}$	3 dB Bandwidth ^[2]	GHz		2.3	
VSWR	Input VSWR $f = 0.1 \text{ to } 1.5 \text{ GHz}$			1.6:1	
	Output VSWR $f = 0.1 \text{ to } 1.5 \text{ GHz}$			2.0:1	
IP_3	Third Order Intercept Point $f = 1.0 \text{ GHz}$	dBm		29.0	
NF	50 Ω Noise Figure $f = 1.0 \text{ GHz}$	dB		6.5	
t_{D}	Group Delay $f = 1.0 \text{ GHz}$	psec		180	
V_{d}	Device Voltage	V	6.7	8.4	10.1
dV/dT	Device Voltage Temperature Coefficient	mV/°C		-16.0	

Notes:

1. The recommended operating current range for this device is 60 to 100 mA. Typical performance as a function of current is on the following page.
2. Referenced from 0.1 GHz Gain (G_{P}).

MSA-0504 Typical Scattering Parameters ($T_A = 25^\circ\text{C}$, $I_d = 80\text{ mA}$)

Freq. MHz	S_{11}		S_{21}			S_{12}			S_{22}		k
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	
5	.54	-43	14.7	5.43	160	-18.4	.120	37	.63	-39	0.60
25	.24	-112	9.3	2.92	155	-13.8	.204	12	.24	-101	0.99
50	.18	-142	8.1	2.54	161	-13.7	.206	3	.16	-125	1.17
100	.14	-156	7.8	2.45	166	-13.7	.207	3	.13	-137	1.18
200	.14	-168	7.6	2.40	163	-13.7	.206	1	.13	-146	1.20
400	.14	-174	7.5	2.37	150	-13.7	.206	1	.16	-143	1.19
600	.14	-175	7.4	2.34	137	-13.6	.208	-1	.20	-144	1.18
800	.15	-174	7.2	2.29	124	-13.5	.211	-1	.25	-148	1.15
1000	.17	-174	7.0	2.24	111	-13.6	.209	-3	.29	-154	1.14
1500	.23	-179	6.4	2.09	80	-13.3	.216	-4	.37	-168	1.06
2000	.33	171	5.5	1.88	51	-12.8	.230	-10	.48	178	0.91
2500	.42	156	4.3	1.64	27	-13.0	.224	-12	.51	165	0.90
3000	.49	146	3.2	1.44	6	-12.8	.230	-11	.55	157	0.92

A model for this device is available in the DEVICE MODELS section.

Typical Performance, $T_A = 25^\circ\text{C}$

(unless otherwise noted)

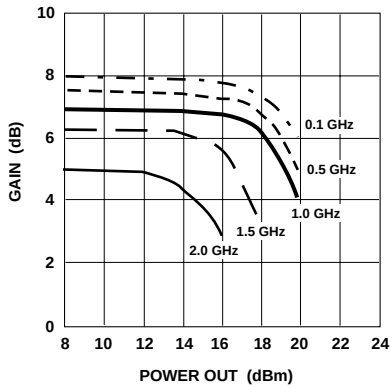


Figure 1. Typical Gain vs. Power Out, $T_A = 25^\circ\text{C}$, $I_d = 80\text{ mA}$.

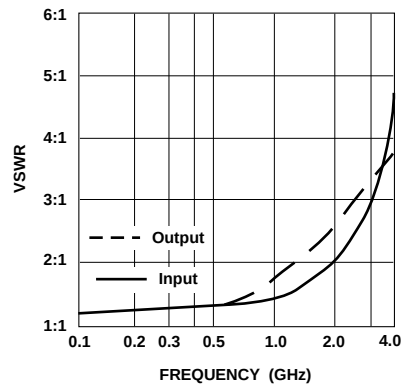


Figure 2. VSWR vs. Frequency, $I_d = 80\text{ mA}$.

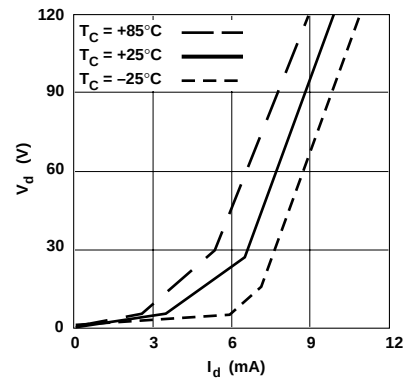


Figure 3. Device Current vs. Voltage.

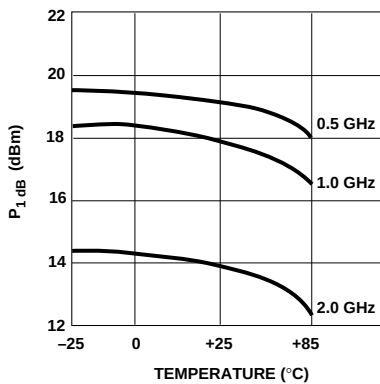


Figure 4. Output Power at 1 dB Gain Compression, vs. Case Temperature, $I_d = 80\text{ mA}$.

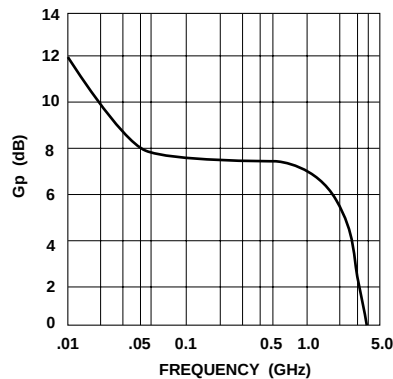


Figure 5. Gain vs. Frequency, $I_d = 80\text{ to }100\text{ mA}$.

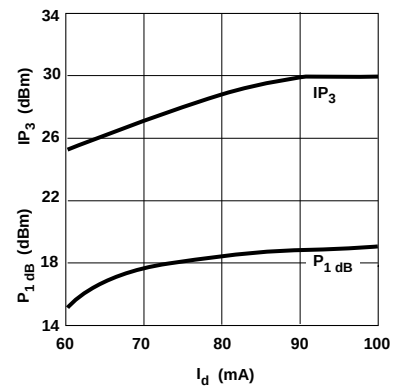


Figure 6. Output Power at 1 dB Gain Compression, Third Order Intercept vs. Current, $f = 1.0\text{ GHz}$.

04A Plastic Package Dimensions

